

EMB1S THRU EMB6S

Single Phase 0.8AMP Super Fast Glass Passivated Bridge Rectifier

Features

- Glass Passivated Die Construction
- Low leakage
- · Ideal for printed circuit board
- Surge overload rating-30A peak
- Designed for Surface Mount Application
- Plastic Material-UL Flammability 94V-0

Mechanical Data

- Case:Reliable low cost construction
 utilizing molded plastic technique
- Terminals:Plated Leads Solderable per MIL-STD-202,Method208
- Polarity:As Marked on Case
- Mounting Position:Any
- Marking:Type Number

Case: MBS 0.106(2.7) 0.090(2.3)0.008(0.2) Max +0.275(7.0) 0.161(4.1) $\overline{0, 142(3, 6)}$ Max 0.030(0.75) 0.012(0.3)0.010(0.25) 0.006(0.15) 0.028(0.7) 0.020(0.5) 0.195(4.95)0.177(4.5)0.110(2.8) 0.109(2.7) 0.091(2.3)0,091(2,3)

dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Rating at 25° C ambient temperature unless otherwise specified. Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

TYPE NUMBER	SYMBOL	EMB1S	EMB2S	EMB4S	EMB6S	UNITS
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	Vrrm	100	200	400	600	v
	VRWM					
	VDC					
RMS Reverse Voltage	VRMS	70	140	280	420	V
Average Rectified Output Current (Note 1)@Tc=100℃ (Note 2)@Tc=100℃	IF(AV)	0.5 0.8				А
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	Іғѕм	30				А
I ² t Rating for Fusing (t < 8.3ms)	l²t	3.735			A ² s	
Forward Voltage per element @IF=0.8A	Vfm	0.95 1.3		1.75	V	
Peak Reverse Current @Tյ=25℃ At Rated DC Blocking Voltage @Tյ=125℃	lĸ	5.0 100			uA	
Maximum reverse recovery time (Note 3)	T _{RR}	35			ns	
Typical Junction Capacitance (Note 4)	CJ	13				pF
Typical Thermal Resistance	Reja	60				°C/W
	Rejl	16				
Operating and Storage Temperature Range	TJ,TSTG	-55to+150				°C

Note:1. Mounted on glass epoxy PC board with 1.3mm² solder pad.

2. Mounted on aluminum substrate PC board with 1.3mm² solder pad.

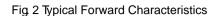
- 3. Reverse Recovery Test Conditions: IF=0.5A, IR=1A, Irr=0.25A.
- 4. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.



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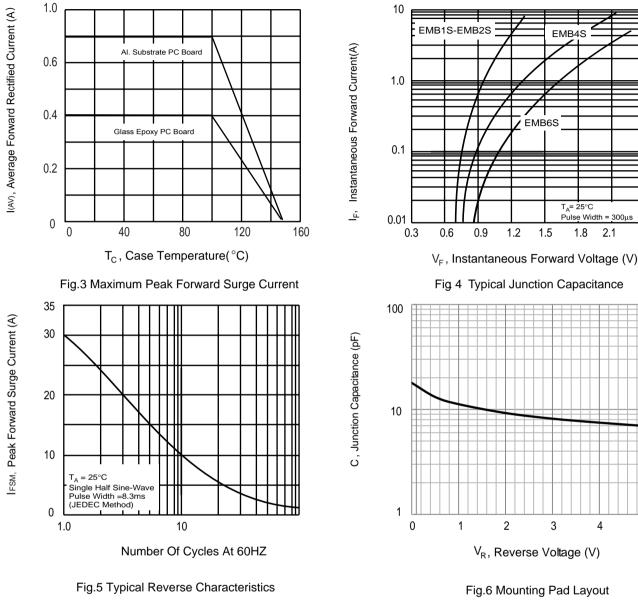
Fig1 Output Current Derating Curve

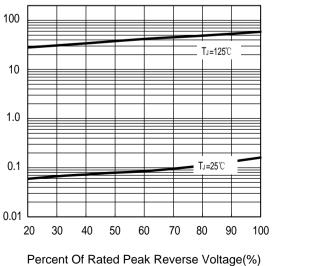


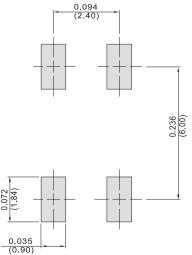
2.1

4

5







Instantaneous Reverse Current(uA)



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